## TKN/KS/16/5856

# Bachelor of Science (B.Sc.) Semester—IV (C.B.S.)

### **Examination**

## **PHYSICS**

(Solid State Electronics and Molecular Physics)

## Paper—II

Time—Three Hours]

[Maximum Marks—50

**N.B.**:— (1) **ALL** questions are compulsory.

(2) Draw neat diagrams wherever necessary.

## **EITHER**

1. (A) What is transistor action? Discuss the input and output characteristics of a transistor in CB mode.

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- (B) (i) Discuss the graphical method of analysis of working of a transistor as an amplifier in CE mode.
  - (ii) A junction transistor is operated in CB mode. If  $\alpha = 0.941$ .

Calculate  $\beta$  of the transistor.

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- (E) How does quantum theory explain Raman effect ?  $2\frac{1}{2}$
- (F) The wavelength of an exciting line in an experiment is 4358 Å and the Stoke's line is at 4458 Å. Find the wavelength of antistokes line.

## 5. Attempt any **TEN** :—

- (i) What is a photovoltaic cell?
- (ii) State the majority and minority charge carriers in N-type and p-type semiconductors.
- (iii) Explain thermal runaway.
- (iv) Draw symbol of N-channel and P-channel depletion MOSFET.
- (v) Explain why a deplection region in JFET is Wedge shaped.
- (vi) Draw the circuit symbols of N-channel and P-channel JFET.
- (vii) State any two failures of Born-Oppenheimer approximation.

- (B) (i) Explain the static drain characteristics and transfer characteristics of enhancement MOSFETs. 3
  - (ii) State the special features of MOSFETs. 2

#### OR

- (C) Draw the circuit diagram to study the characteristics of an N- channel FET and discuss the transfer characteristic curve.
- (D) Obtain expressions for the input impedance and output impedance for a common-source JFET amplifier.

 $2\frac{1}{2}$ 

- (E) A common-source JFET amplifier has a load resistance  $R_L = 500 \text{ k}\Omega$ . If ac drain resistance  $r_d = 100 \text{ k}\Omega$  and voltage gain is 20, calculate the amplification factor.
- (F) Differentiate between JFET and BJT. 2½

#### **EITHER**

(A) Derive an expression for spacing between energy levels of vibrational spectra. Show that vibrational energy levels are equally spaced.

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- (B) (i) Draw and explain energy level diagram in vibrational- rotational spectra.
  - (ii) Calculate the frequency of vibration in v=0 level of CO molecule, if its force constant is 1870 N/m and reduced mass is  $11.4\times10^{-27}$  kg.

#### OR

- (C) Assuming the expression for rotational energy of a diatomic molecule, show that the energy levels are not equally spaced.
- (D) State the selection rule for rotational spectra. Draw and explain the rotational frequency spectrum of a rigid diatomic molecule.
- (E) Obtain an expression for the moment of inertia of two nuclei about their centre of mass of HCl molecule.
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- (F) The number of lines in a rotational band is given by :

$$\nabla_{r'} = 1000 (2n - 1) \text{ cm}^{-1}$$

$$\nabla_{r''} = -1000 (2n + 1) \text{ cm}^{-1}. \text{ for}$$
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positive and negative values of n. Calculate moment of inertia of the molecule.

Given:

$$h = 6.63 \times 10^{-27} \text{ erg-sec.}$$
  
 $c = 3 \times 10^{10} \text{ cm/sec.}$  2½

#### **EITHER**

4. (A) What is Raman effect? Obtain the expression for Raman shift.

State the applications of Raman effect and explain any one in detail.

- (B) (i) State and explain the Franck—Condon principle.
  What are its limitations?
  - (ii) In observing the Raman spectrum, of a sample using 2537 Å as the exciting line, one gets a Stokes line at 2683 Å. Deduce the Raman shift in cm<sup>-1</sup>.

#### OR

(C) Describe the electronic spectra of diatomic molecules.  $2\frac{1}{2}$ 

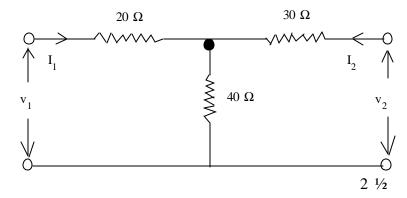
(D) Distinguish between NMR and ESR spectroscopy.

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OR

- (C) Explain the construction and working of a Solar Cell. 2½
- (D) What is load line? How will you draw a d.c. load line on the output characteristics of a transistor?
- (E) Derive an expression for stability factor in terms of  $I_{CBO}^{\phantom{\dagger}}.$
- (F) Determine the h-parameters for the following circuit:



**EITHER** 

(A) What is a MOSFET? State the principle on which
it works. Sketch the structure of a p-channel
enhancement MOSFET. Explain its working.

- (viii) Calculate the frequency of the specctral line if change in energy in vibrational energy level is 0.1 eV.
- (ix) Which molecule will exhibit vibration spectra,  $H_2$  or HCl. Why ?
- (x) Write the applications of ESR Spectroscopy.
- (xi) State the differences between Raman and Fluorescent scattering.
- (xii) Define dissociation energy.  $1 \times 10$

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